

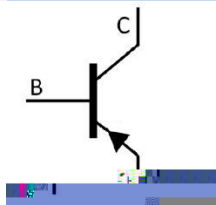
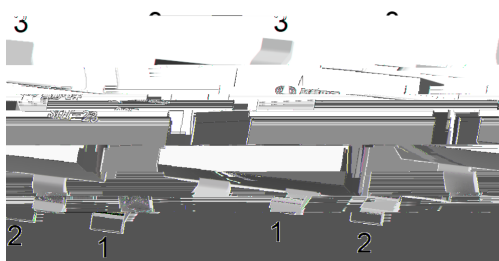
Rev.B May.-2025

VRW056 SQS Silicon PNP transistor in a SOT-23 Plastic Package.

h_{IH} $h_{FH+V_{AW}}$ DHF0T434

High DC Current Gain, Low Collector to Emitter Saturation Voltage, Qualified to AEC-Q101 Standards for High Reliability, HF Product.

General purpose amplifier and switching, Meet the stringent requirements of automotive applications.



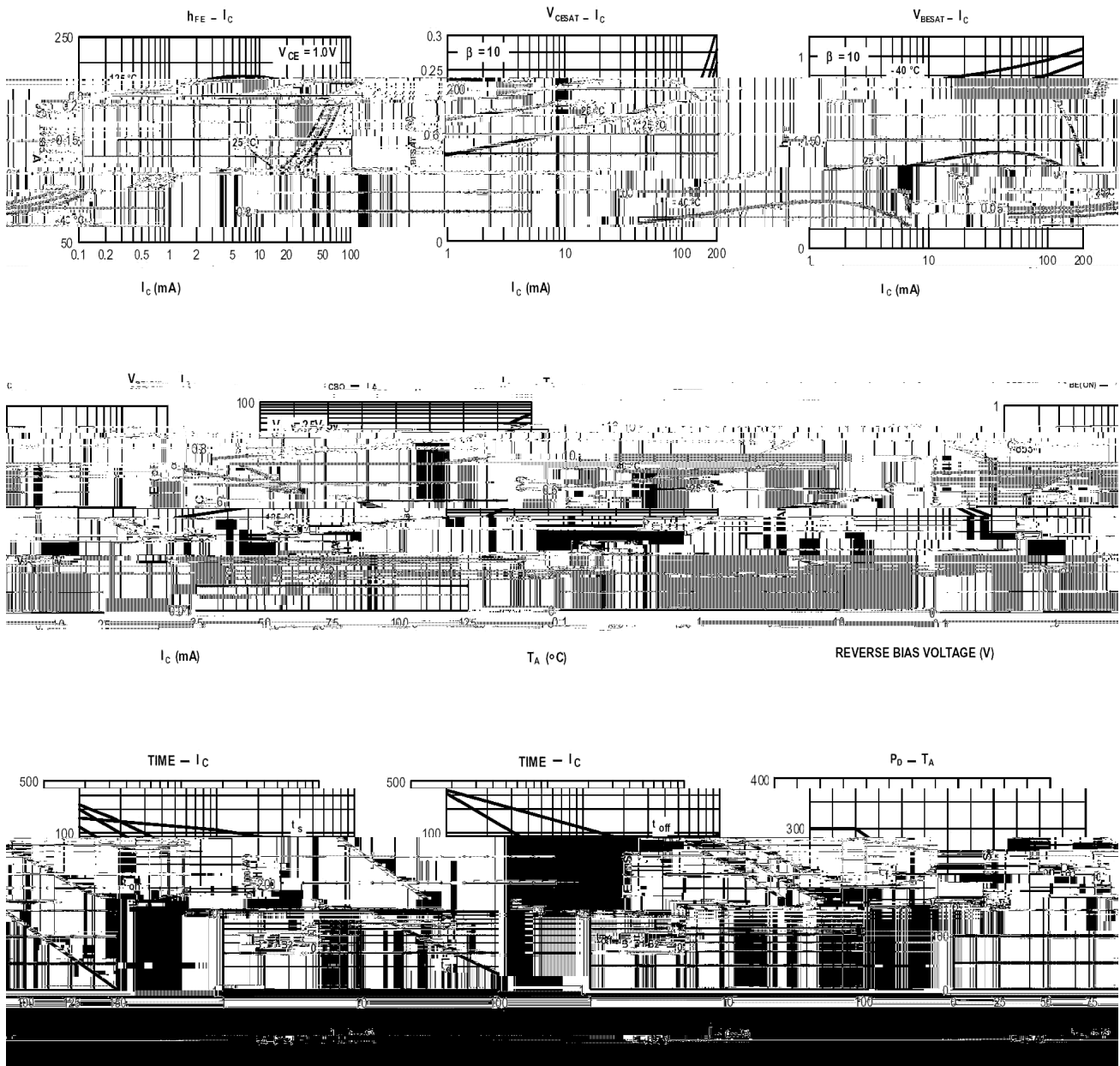
PIN 1 Base

PIN 2 Emitter

PIN 3 Collector

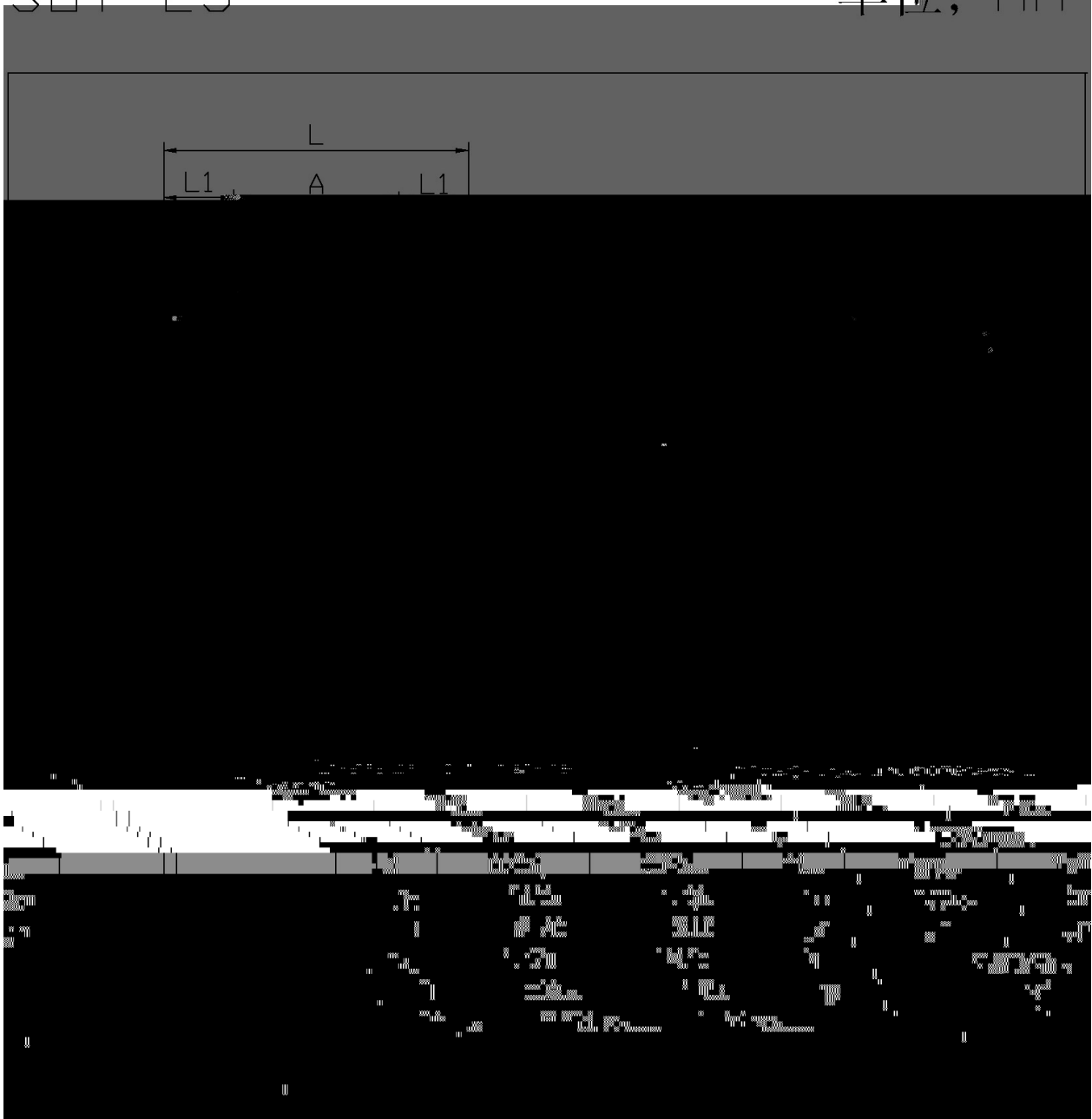
h_{FE} Range	100 300
Marking	· Q2A

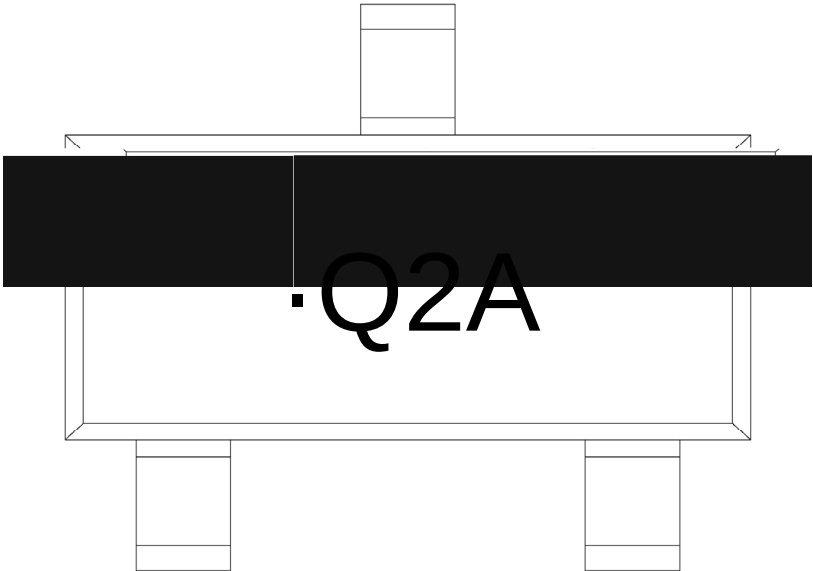
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Transition Frequency	f_T	$V_{CE}=-20V$ $I_C=-10mA$ $f=100MHz$	250			MHz
Output Capacitance	C_{ob}	$V_{CB}=-5.0V$ $f=1.0MHz$			4.5	pF
Storage Time	t_{stg}	$V_{CC}=-3.0V$ $I_C=-10mA$ $I_{B1}=-I_{B2}=-1.0mA$			225	ns
Fall Time	t_f	$V_{CC}=-3.0V$ $I_C=-10mA$ $I_{B1}=-I_{B2}=-1.0mA$			75	ns
Delay Time	t_d	$V_{CC}=-3.0V$ $V_{BE}=-0.5V$ $I_C=-10mA$ $I_{B1}=-1.0mA$			35	ns
Rise Time	t_r	$V_{CC}=-3.0V$ V				



SOT-23

单位: mm





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Q

2A

Note:

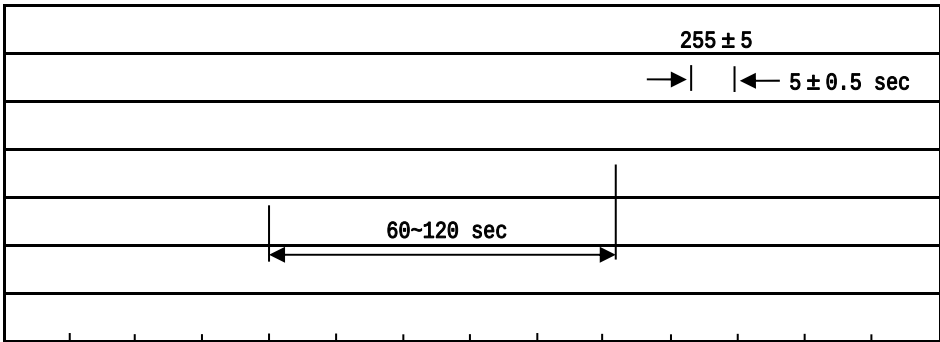
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Identify

Q: Automobile halogen-free product Code

2A Product Type Code

Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-------|-----|-----------|---|--|
| 1 | 150 | 200 | 60 | 120sec; | 1.Preheating:150~200 , Time:60~120sec. |
| 2 | 255±5 | | 5±0.5sec; | 2.Peak Temp.:255±5 , Duration:5±0.5sec. | |
| 3 | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. | |

260±5 10±1 sec. Temp.:260±5 Time:10±1 sec

/ REEL

Package Type	Units					Dimension (unit mm ³)		
	Units/Reel	Reels/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Reel	Inner Box	Outer Box
SOT-23	3,000	10	30,000	6	180,000	7 ×8	180×120×180	390×385×205